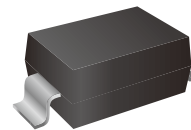




Description

RHP0300AW Thyristor solid state protection thyristor protect telecommunications equipment such as modems, line cards, fax machines, and other CPE.

The RHP0300AW device is used to enable equipment to meet various regulatory requirements including GR 1089, ITU K.20, K.21 and K.45, IEC 60950, and TIA-968 (formerly known as FCC Part 68).



Features

Compared to surge suppression using other technologies, The RHP0300AW device offers absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). The RHP0300AW device:

- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipation typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigue
- Have low capacitance, making them ideal for high-speed transmission equipment
- Meets MSL level 1, per J-STD-020
- Lead free in comply with EU RoHS 2011/65/EU directives



Ordering Information

Part Number	Marking	Shipping	Reel
RHP0300AW	P030A	8000PCS Tape&Reel	13 inches

Thermal Considerations

Parameter	Symbol	Value	Unit
Operating Junction Temperature	T_J	-40 to +150	°C
Storage Temperature Range	T_S	-40 to +150	°C
Junction to Ambient on printed circuit	$R_{\theta JA}$	120	°C/W

Electrical Characteristics

Part Number	V_{DRM} (V)	V_S (V)	V_T (V)	I_{DRM} (μA)	I_S (mA)	I_T (A)	I_H (mA)	C_O (pF)
RHP0300AW	25	40	4	5	800	2.2	50	50

Notes:

- All measurements are made at an ambient temperature of 25°C. I_{PP} applies to -40°C through +85°C temperature range.
- Off-state capacitance(C_O) is measured at 1 MHz with a 2V bias and is typical value.

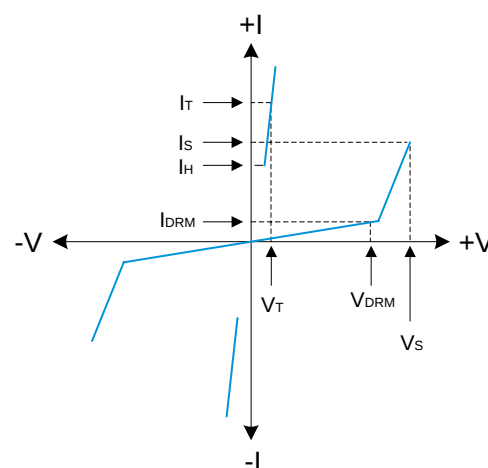


Surge Ratings

I_{PP} 2×10μs (A)	I_{PP} 8×20μs (A)	I_{PP} 10×160μs (A)	I_{PP} 10×560μs (A)	I_{PP} 10×1000μs (A)	I_{TSM} 60Hz (A)	di/dt (A/μs)
150	150	90	50	45	20	500

Electrical Parameters

Parameter	Definition
V_{DRM}	Peak Off-state Voltage – maximum voltage that can be applied while maintaining off state
V_S	Switching Voltage – maximum voltage prior to switching to on state
V_T	On-state Voltage – maximum voltage measured at rated on-state current
I_{DRM}	Leakage Current – maximum peak off-state current measured at V_{DRM}
I_S	Switching Current – maximum current required to switch to on state
I_T	On-state Current – maximum rated continuous on-state current
I_H	Holding Current – typical current required to maintain on state
C_O	Off-state Capacitance – typical capacitance measured in off state
I_{PP}	Peak Pulse Current – maximum rated peak impulse current
I_{TSM}	Peak One-cycle Surge Current – maximum rated one-cycle AC current
di/dt	Rate of Rise of Current – maximum rated value of the acceptable rate of rise in current over time



Characteristics Curves

Fig.1 $t_r \times t_d$ Pulse Wave-form

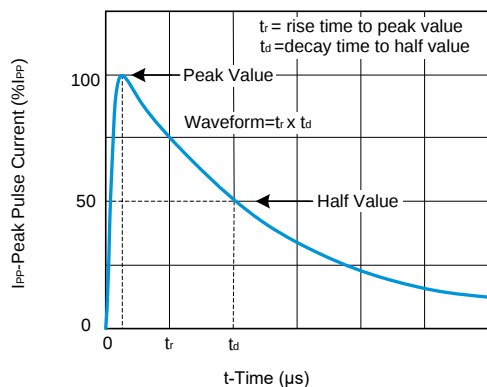


Fig.2 Normalized V_S Change versus Junction Temperature

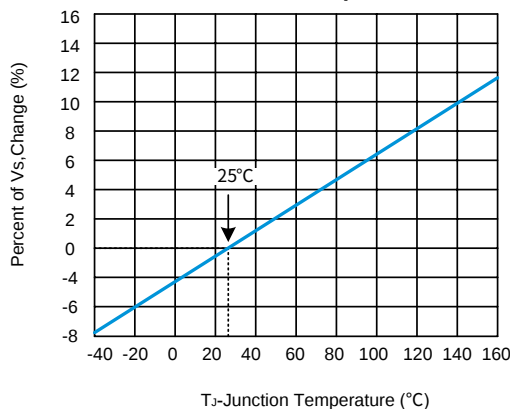
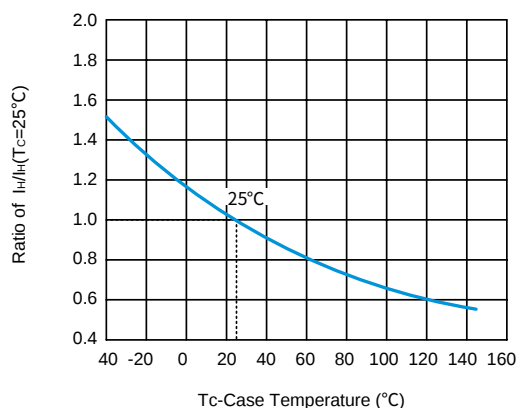


Fig.3 Normalized DC Holding Current versus Case Temperature





Package Outline

SMAWUnit : mm

Top View

Front view

Side view

UNIT		A	C	D	E	H _E	d	e	∠
mm	max	2.00	0.28	3.80	2.60	5.80	1.40	1.20	6°
	min	1.60	0.10	3.40	2.20	5.40	1.00	0.80	

Suggested Pad Layout

SMAWUnit : mm

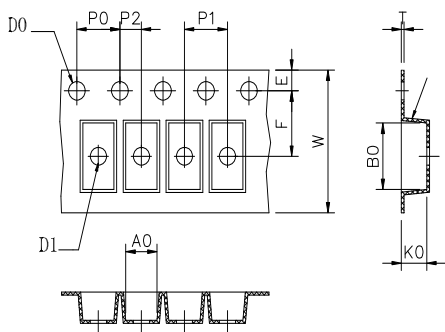
Note:

- 1. Controlling dimension:in millimeters.
- 2. General tolerance:±0.05mm
- 3. The pad layout is for reference purpose only.



Carrier Tape Dimensions

Unit : mm

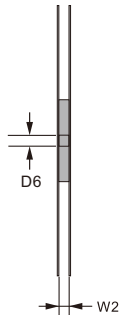
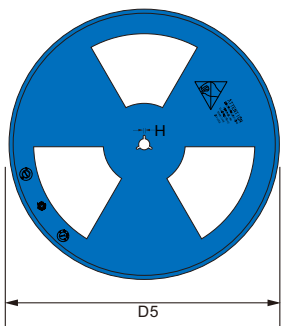


Symbol	Spec	Symbol	Spec
W	12.00±0.10	P1	4.00±0.10
E	1.75±0.10	P2	2.00±0.05
F	5.50±0.05	T	0.25±0.02
D0	1.55±0.05	A0	2.60±0.10
D1	1.50±0.10	B0	5.70±0.10
P0	4.00±0.10	K0	2.00±0.05

Reel Dimensions

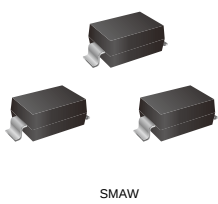
Unit : mm

13" Reel

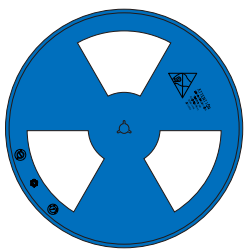


D5	Φ330.0±2.0
D6	Φ13.5±0.5
H	2.5±1.0
W2	12±2.0
Quantity: 8000PCS	

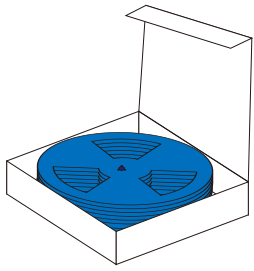
Packaging



8000PCS/Reel

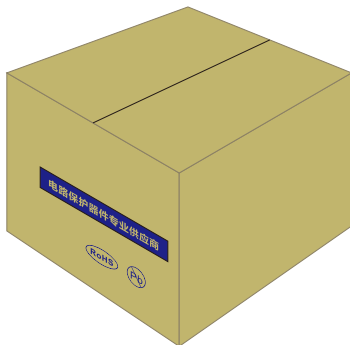


5Reel/Inner Box
40KPCS/Inner Box



Dim(Unit:mm)
340mm*340mm*85mm

Dim(Unit:mm)
360mm*360mm*355mm

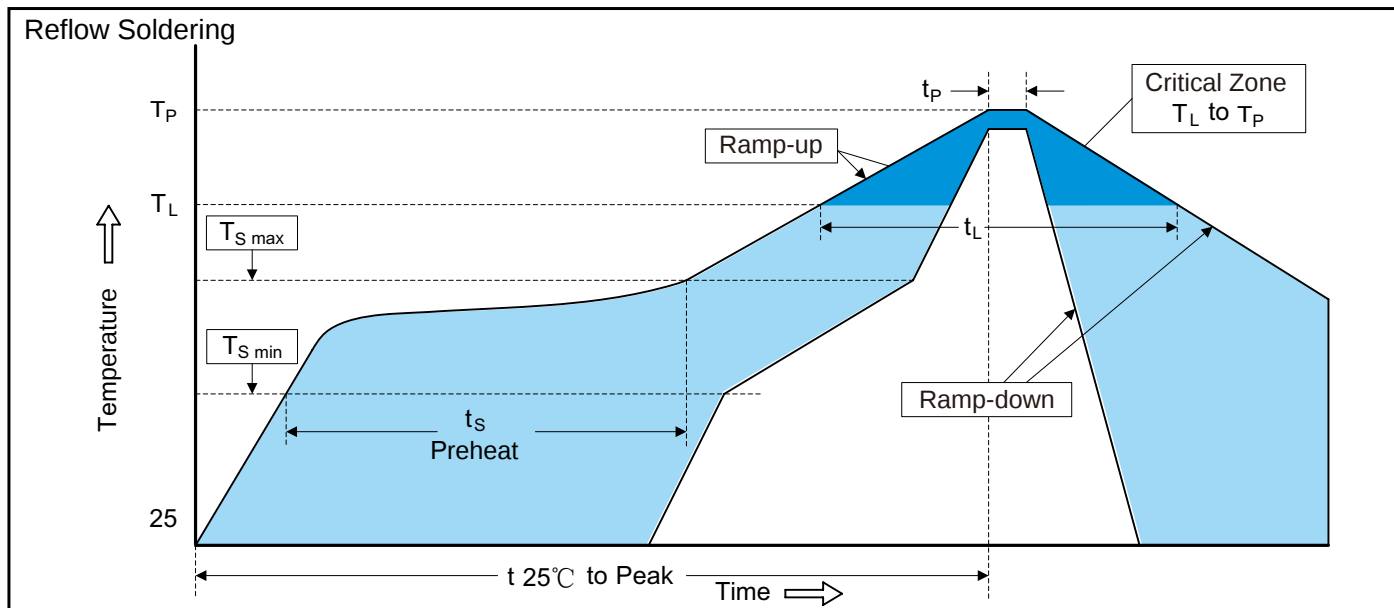


4 Boxes per carton
160KPCS per carton

13 inches Reel



Recommended Soldering Conditions



Recommended Conditions

Profile Feature	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	3°C/second max.
Preheat	
-Temperature Min ($T_{S\ min}$)	150°C
-Temperature Max ($T_{S\ max}$)	200°C
-Time (min to max) (t_s)	60-180 seconds
$T_{S\ max}$ to T_L	
-Ramp-up Rate	3°C/second max.
Time maintained above:	
-Temperature (T_L)	217°C
-Time (t_L)	60-150 seconds
Peak Temperature (T_P)	260°C
Time within 5°C of actual Peak Temperature (t_p)	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.